Accepted Manuscript

Title: Hydrogen gas sensing properties of platinum decorated silicon carbide (Pt/SiC) Nanoballs

Authors: Narendra Singh, Arvind Kumar, Davinder Kaur

PII: S0925-4005(18)30241-7

DOI: https://doi.org/10.1016/j.snb.2018.01.216

Reference: SNB 24065

To appear in: Sensors and Actuators B

Received date: 13-9-2017 Revised date: 9-1-2018 Accepted date: 29-1-2018



Please cite this article as: Narendra Singh, Arvind Kumar, Davinder Kaur, Hydrogen gas sensing properties of platinum decorated silicon carbide (Pt/SiC) Nanoballs, Sensors and Actuators B: Chemical https://doi.org/10.1016/j.snb.2018.01.216

This is a PDF file of an unedited manuscript that has been accepted for publication. As a service to our customers we are providing this early version of the manuscript. The manuscript will undergo copyediting, typesetting, and review of the resulting proof before it is published in its final form. Please note that during the production process errors may be discovered which could affect the content, and all legal disclaimers that apply to the journal pertain.

ACCEPTED MANUSCRIPT

Hydrogen gas sensing properties of platinum decorated silicon carbide (Pt/SiC) Nanoballs

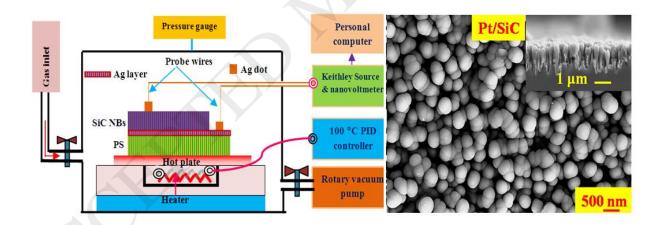
Narendra Singh¹, Arvind Kumar², Davinder Kaur^{1*}

¹Functional Nanomaterials Research Lab, Department of Physics and Center for Nanotechnology, Indian Institute of Technology Roorkee, Roorkee 247667, India

²Nanoscience Laboratory, Institute Instrumentation Centre, Indian Institute of Technology Roorkee, Roorkee 247667, India

*Corresponding author: E-mail: dkaurfph@iitr.ernet.in; Tel.: 91-1332-2285407; FAX: 91-1332-273560

Graphical Abstract:



Highlights:

- Platinum decorated SiC nanoballs (NBs) were grown on porous silicon using RF magnetron sputtering.
- Porous silicon substrates were prepared by metal-assisted chemical etching process.

Download English Version:

https://daneshyari.com/en/article/7140434

Download Persian Version:

https://daneshyari.com/article/7140434

<u>Daneshyari.com</u>